# **CPU 5-Bit Nonsynchronous Buck Controller**

The CS5156H is a 5-bit nonsynchronous N-Channel buck controller. It is designed to provide unprecedented transient response for today's demanding high-density, high-speed logic. The regulator operates using a proprietary control method, which allows a 100 ns response time to load transients. The CS5156H is designed to operate over a 4.25–20 V range ( $V_{\rm CC}$ ) using 12 V to power the IC and 5.0 V or 12 V as the main supply for conversion.

The CS5156H is specifically designed to power Pentium® II processors and other high performance core logic. It includes the following features: on board, 5-bit DAC, short circuit protection, 1.0% output tolerance,  $V_{\rm CC}$  monitor, and programmable Soft Start capability. The CS5156H is backwards compatible with the 4-bit CS5151, allowing the mother board designer the capability of using either the CS5151 or the CS5156H with no change in layout. The CS5156H is available in 16 pin surface mount packages.

#### **Features**

- N-Channel Design
- Excess of 1.0 MHz Operation
- 100 ns Transient Response
- 5-Bit DAC
- Backward Compatible with 4-Bit CS5150H/CS5151H
- 30 ns Gate Rise/Fall Times
- 1.0% DAC Accuracy
- 5.0 V & 12 V Operation
- Remote Sense
- Programmable Soft Start
- Lossless Short Circuit Protection
- V<sub>CC</sub> Monitor
- Adaptive Voltage Positioning
- V<sup>2™</sup> Control Topology
- Current Sharing
- Overvoltage Protection



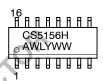
#### ON Semiconductor<sup>™</sup>

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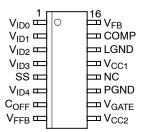


SOIC-16 D SUFFIX CASE 751B



A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week

#### PIN CONNECTIONS



#### **ORDERING INFORMATION**

Device	Package	Shipping
CS5156HGD16	SO-16	48 Units/Rail
CS5156HGDR16	SO-16	2500 Tape & Reel

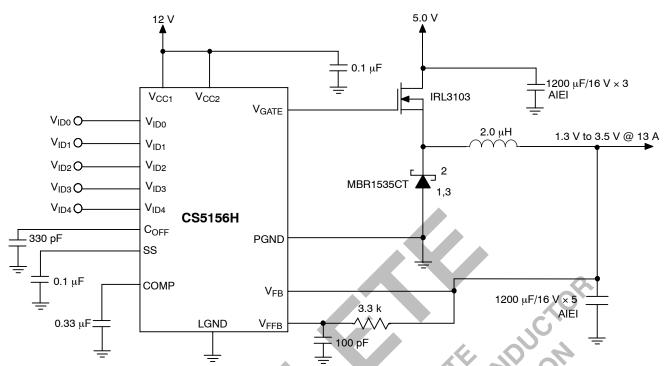


Figure 1. Application Diagram, Switching Power Supply for Core Logic – Pentium<sup>®</sup> II Processor

#### **ABSOLUTE MAXIMUM RATINGS\***

	Rating	Value	Unit
Operating Junction Temperature, TJ	14, 40 2,	0 to 150	°C
Lead Temperature Soldering:	Reflow: (SMD styles only) (Note 1)	230 peak	°C
Storage Temperature Range, T <sub>S</sub>	110,011,01	-65 to +150	°C
ESD Susceptibility (Human Body Model)	C 10 C	2.0	kV

<sup>1. 60</sup> second maximum above 183°C.

#### **ABSOLUTE MAXIMUM RATINGS**

Pin Name	Max Operating Voltage	Max Current
V <sub>CC1</sub>	16 V/-0.3 V	25 mA DC/1.5 A peak
V <sub>CC2</sub>	20 V/-0.3 V	20 mA DC/1.5 A peak
SS	6.0 V/-0.3 V	–100 μΑ
COMP	6.0 V/-0.3 V	200 μΑ
V <sub>FB</sub>	6.0 V/-0.3 V	-0.2 μΑ
C <sub>OFF</sub>	6.0 V/-0.3 V	-0.2 μΑ
$V_{FFB}$	6.0 V/-0.3 V	-0.2 μΑ
$V_{\text{ID0}} - V_{\text{ID4}}$	6.0 V/-0.3 V	-50 μΑ
V <sub>GATE</sub>	20 V/-0.3 V	100 mA DC/1.5 A peak
LGND	0 V	25 mA
PGND	0 V	100 mA DC/1.5 A peak

<sup>\*</sup>The maximum package power dissipation must be observed.

 $\begin{array}{l} \textbf{ELECTRICAL CHARACTERISTICS} & (0 ^{\circ}\text{C} < T_{A} < +70 ^{\circ}\text{C}; \ 0 ^{\circ}\text{C} < T_{J} < +125 ^{\circ}\text{C}; \ 8.0 \ V < V_{CC1} < 14 \ V; \ 5.0 \ V < V_{CC2} < 20 \ V; \\ \textbf{DAC Code: V}_{ID4} = V_{ID2} = V_{ID1} = V_{ID0} = 1; \ V_{ID3} = 0; \ CV_{GATE} = 1.0 \ nF; \ C_{OFF} = 330 \ pF; \ C_{SS} = 0.1 \ \mu F, \ unless \ otherwise \ specified.) \\ \end{array}$ 

Error Amplifier           V <sub>FB</sub> Bias Current         V <sub>FB</sub> = 0 V         -         0.3         1.0         μA           Open Loop Gain         1.25 V < V <sub>COMP</sub> < 5.0 V         50         60         -         dB           Unity Gain Bandwidth         Note 2         500         3000         -         kHz           COMP SINK Current         V <sub>COMP</sub> = 1.5 V; V <sub>FB</sub> = 3.0 V; V <sub>SS</sub> > 2.0 V         0.4         2.5         8.0         mA           COMP SURICE Current         V <sub>COMP</sub> = 1.2 V; V <sub>FB</sub> = 2.7 V         0.4         1.0         1.6         mA           COMP CLAMP Current         V <sub>COMP</sub> = 0 V; V <sub>FB</sub> = 2.7 V         0.4         1.0         1.6         mA           COMP Low Voltage         V <sub>FB</sub> = 2.7 V; V <sub>SS</sub> = 5.0 V         4.0         4.3         5.0         V           COMP Low Voltage         V <sub>FB</sub> = 3.0 V         -         160         600         mV           PSRR         8.0 V < V <sub>CCI</sub> < 14 V @ 1.0 kHz; Note 2         60         85         dB           V <sub>CCT</sub> Monitor         Start Threshold         Output switching         3.75         3.90         4.05         V           Stop Threshold         Output not switching         3.75         3.90         4.05         V           Vota	Characteristic	Test Conditions	Min	Тур	Max	Unit
Open Loop Gain         1.25 V < V <sub>COMP</sub> < 4.0 V; Note 2         50         60         -         dB           Unity Gain Bandwidth         Note 2         500         3000         -         kHz           COMP SINK Current         V <sub>COMP</sub> = 1.5 V; V <sub>FB</sub> = 3.0 V; V <sub>SS</sub> > 2.0 V         0.4         2.5         8.0         mA           COMP SURCE Current         V <sub>COMP</sub> = 0.7; V <sub>FB</sub> = 2.7 V; V <sub>SS</sub> = 5.0 V         0.4         1.0         1.6         mA           COMP CLAMP Current         V <sub>COMP</sub> = 0.V; V <sub>FB</sub> = 2.7 V         0.4         1.0         1.6         mA           COMP LLAW Voltage         V <sub>FB</sub> = 2.7 V; V <sub>SS</sub> = 5.0 V         4.0         4.3         5.0         V           COMP Low Voltage         V <sub>FB</sub> = 3.0 V         -         160         600         mV           PSRR         8.0 V < V <sub>CC1</sub> < 14 V @ 1.0 kHz; Note 2	Error Amplifier					
Unity Gain Bandwidth	V <sub>FB</sub> Bias Current	V <sub>FB</sub> = 0 V	-	0.3	1.0	μΑ
COMP SINK Current         V <sub>COMP</sub> = 1.5 V; V <sub>FB</sub> = 3.0 V; V <sub>SS</sub> > 2.0 V         0.4         2.5         8.0         mA           COMP SOURCE Current         V <sub>COMP</sub> = 1.2 V; V <sub>FB</sub> = 2.7 V; V <sub>SS</sub> = 5.0 V         30         50         80         μA           COMP CLAMP Current         V <sub>COMP</sub> = 0 V; V <sub>FB</sub> = 2.7 V; V <sub>SS</sub> = 5.0 V         0.4         1.0         1.6         mA           COMP High Voltage         V <sub>FB</sub> = 2.7 V; V <sub>SS</sub> = 5.0 V         4.0         4.3         5.0         V           COMP Low Voltage         V <sub>FB</sub> = 3.0 V         -         160         600         mV           PSRR         8.0 V < V <sub>CC1</sub> < 14 V @ 1.0 kHz; Note 2	Open Loop Gain	1.25 V < V <sub>COMP</sub> < 4.0 V; Note 2	50	60	-	dB
COMP SOURCE Current   VCOMP = 1.2 V; VFB = 2.7 V; VSS = 5.0 V	Unity Gain Bandwidth	Note 2	500	3000	-	kHz
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	COMP SINK Current	$V_{COMP} = 1.5 \text{ V}; V_{FB} = 3.0 \text{ V}; V_{SS} > 2.0 \text{ V}$	0.4	2.5	8.0	mA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	COMP SOURCE Current	V <sub>COMP</sub> = 1.2 V; V <sub>FB</sub> = 2.7 V; V <sub>SS</sub> = 5.0 V	30	50	80	μΑ
COMP Low Voltage         V <sub>FB</sub> = 3.0 V         -         160         600         mV           PSRR         8.0 V < V <sub>CC1</sub> < 14 V @ 1.0 kHz; Note 2	COMP CLAMP Current	V <sub>COMP</sub> = 0 V; V <sub>FB</sub> = 2.7 V	0.4	1.0	1.6	mA
PSRR         8.0 V < V <sub>CC1</sub> < 14 V @ 1.0 kHz; Note 2         60         85         dB           V <sub>CC1</sub> Monitor           Start Threshold         Output switching         3.75         3.90         4.05         V           Stop Threshold         Output not switching         3.70         3.85         4.00         V           Hysteresis         Start – Stop         50         -         mV           VGATE         W         M         W         M         W         M         W         M         M         M         M         M         M         M         M         M         M         M         M         M <t< td=""><td>COMP High Voltage</td><td>V<sub>FB</sub> = 2.7 V; V<sub>SS</sub> = 5.0 V</td><td>4.0</td><td>4.3</td><td>5.0</td><td>V</td></t<>	COMP High Voltage	V <sub>FB</sub> = 2.7 V; V <sub>SS</sub> = 5.0 V	4.0	4.3	5.0	V
VCc1 Monitor         Start Threshold         Output switching         3.75         3.90         4.05         ∨           Stop Threshold         Output not switching         3.70         3.85         4.00         ∨           Hysteresis         Start-Stop         -         50         -         mV           VGATE         -         50         -         mV           VUSOURCE Sat at 100 mA         Measure VCC2 - VGATE         1.2         2.0         V           Out SINK Sat at 100 mA         Measure VGATE - VPGND         -         1.0         1.5         V           Out Rise Time         1.0 V < VGATE - VPGND	COMP Low Voltage	V <sub>FB</sub> = 3.0 V	-/	160	600	mV
Start Threshold   Output switching   3.75   3.90   4.05   V     Stop Threshold   Output not switching   3.70   3.85   4.00   V     Hysteresis   Start-Stop   −   60   −   mV     VGATE     Out SOURCE Sat at 100 mA   Measure VC2− VGATE   1.2   2.0   V     Out SINK Sat at 100 mA   Measure VC4− VGATE   −   1.0   1.5   V     Out Rise Time   1.0 V × VGATE < 9.0 V; VCC1 = VCC2 = 12 V   −   30   50   ns     Out Fall Time   9.0 V > VGATE < 1.0 V; VCC1 = VCC2 = 12 V   −   30   50   ns     Shoot-Through Current   Note 2   −   −   50   mA     VGATE Resistance   Resistor to LGND. Note 2   −   −   50   mA     VGATE Schottky   LGND to VGATE @ 10 mA   −   600   800   mV     Soft Start (SS)     Charge Time   −   1.6   3.3   5.0   ms     Pulse Period   25   100   200   ms     Duty Cycle   (Charge Time /Pulse Period) × 100   1.0   3.3   6.0   %     COMP Clamp Voltage   VGATE = LDW   0.9   1.0   1.1   V     VFFB SS Fault Disable   VGATE = LDW   0.9   1.0   1.1   V     PWM Comparator   VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V   −   100   125   ns     Transient Response   VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V   −   100   125   ns     Start Start Start Start Response   VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V   −   100   125   ns     Transient Response   VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V   −   100   125   ns     Tansient Response   VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V   −   100   125   ns     Tansient Response   VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V   −   100   125   ns     Tansient Response   VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V   −   100   125   ns     Tansient Response   VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V   −   100   125   ns     Tansient Response   VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V   −   100   125   ns     Tansient Response   VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V	PSRR	8.0 V < V <sub>CC1</sub> < 14 V @ 1.0 kHz; Note 2	60	85	0	dB
Stop Threshold         Output not switching         3.70         3.85         4.00         V           VarE           Start-Stop         50         -         mV           VGATE         50         -         mV           VGATE         1.2         2.0         V           Out SOURCE Sat at 100 mA         Measure VGATE - VPGND         -         1.0         1.5         V           Out SINK Sat at 100 mA         Measure VGATE - VPGND         -         1.0         1.5         V           Out Rise Time         1.0 V < VGATE > 9.0 V; VCC1 = VCC2 = 12 V         -         30         50         ns           Out Fall Time         9.0 V > VGATE > 1.0 V; VCC1 = VCC2 = 12 V         -         30         50         ns           Shoot-Through Current         Note 2         -         -         50         mA           VGATE Resistance         Resistor to LGND. Note 2         20         50         100         kΩ           VGATE Schottky         LGND to VGATE ® 10 mA         -         600         800         mV           Soft Start (SS)           Charge Time / Pulse Period) × 100         1.0 <td< td=""><td>V<sub>CC1</sub> Monitor</td><td></td><td></td><td></td><td>,0,</td><td></td></td<>	V <sub>CC1</sub> Monitor				,0,	
Hysteresis         Start-Stop         50         -         mV           VGATE         1.2         2.0         V           Out SUNK Sat at 100 mA         Measure V <sub>CC2</sub> - V <sub>PGND</sub> -         1.0         1.5         V           Out Rise Time         1.0 V < V <sub>GATE</sub> < 9.0 V · V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V         -         30         50         ns           Shoot-Through Current         Note 2         -         -         50         mA           V <sub>GATE</sub> Resistance         Resistor to LGND. Note 2         20         50         100         kΩ           V <sub>GATE</sub> Schottky         LGND to V <sub>GATE</sub> @ 10 mA         -         600         800         mV           Soft Start (SS)           Charge Time         -         1.6         3.3         5.0         ms           Pulse Period         25         100         200         ms           Duty Cycle         (Charge Time /Pulse Period) × 100         1.0         3.3         6.0         %           COMP Clamp Voltage         V <sub>FB</sub> = 0 V; V <sub>SS</sub> = 0         0.50         <	Start Threshold	Output switching	3.75	3.90	4.05	V
VGATE         Out SOURCE Sat at 100 mA         Measure V <sub>CC2</sub> - V <sub>GATE</sub> -         1.2         2.0         V           Out SINK Sat at 100 mA         Measure V <sub>GATE</sub> - V <sub>PGND</sub> -         1.0         1.5         V           Out Rise Time         1.0 V < V <sub>GATE</sub> < 9.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V         -         30         50         ns           Out Fall Time         9.0 V > V <sub>GATE</sub> > 1.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V         -         30         50         ns           Shoot-Through Current         Note 2         -         -         50         mA           V <sub>GATE</sub> Resistance         Resistor to LGND. Note 2         20         50         100         kΩ           V <sub>GATE</sub> Schottky         LGND to V <sub>GATE</sub> @ 10 mA         -         600         800         mV           Soft Start (SS)           Charge Time         -         1.6         3.3         5.0         ms           Pulse Period         25         100         200         ms           Duty Cycle         (Charge Time /Pulse Period) × 100         1.0         3.3         6.0         %           COMP Clamp Voltage         V <sub>FB</sub> = 0 V; V <sub>SS</sub> = 0         0.50         0.95         1.10         V           V <sub>FE</sub>	Stop Threshold	Output not switching	3.70	3.85	4.00	V
	Hysteresis	Start-Stop		50	<u>_</u>	mV
Out SINK Sat at 100 mA         Measure V <sub>GATE</sub> – V <sub>PGND</sub> -         1.0         1.5         V           Out Rise Time         1.0 V < V <sub>GATE</sub> < 9.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V         -         30         50         ns           Out Fall Time         9.0 V > V <sub>GATE</sub> > 1.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V         -         30         50         ns           Shoot-Through Current         Note 2         -         -         50         mA           V <sub>GATE</sub> Resistance         Resistor to LGND. Note 2         20         50         100         kΩ           V <sub>GATE</sub> Schottky         LGND to V <sub>GATE</sub> @ 10 mA         -         600         800         mV           Soft Start (SS)           Charge Time         -         1.6         3.3         5.0         ms           Pulse Period         25         100         200         ms           Duty Cycle         (Charge Time /Pulse Period) × 100         1.0         3.3         6.0         %           COMP Clamp Voltage         V <sub>FB</sub> = 0 V; V <sub>SS</sub> = 0         0.50         0.95         1.10         V           V <sub>GATE</sub> = Low         0.9         1.0         1.1         V           Pulse Period Vigate = Low         0.9         1.	V <sub>GATE</sub>		CC			
Out Rise Time         1.0 V < V <sub>GATE</sub> < 9.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V         30         50         ns           Out Fall Time         9.0 V > V <sub>GATE</sub> > 1.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V         -         30         50         ns           Shoot-Through Current         Note 2         -         -         50         mA           V <sub>GATE</sub> Resistance         Resistor to LGND. Note 2         20         50         100         kΩ           V <sub>GATE</sub> Schottky         LGND to V <sub>GATE</sub> @ 10 mA         -         600         800         mV           Soft Start (SS)           Charge Time         -         1.6         3.3         5.0         ms           Pulse Period         25         100         200         ms           Duty Cycle         (Charge Time /Pulse Period) × 100         1.0         3.3         6.0         %           COMP Clamp Voltage         V <sub>FB</sub> = 0 V; V <sub>SS</sub> = 0         0.50         0.95         1.10         V           V <sub>GET</sub> = Low         0.9         1.0         1.1         V           Pulse Tult Disable         V <sub>GATE</sub> = Low         0.9         1.0         1.1         V           Pulse Tult Pulse Period)         -         -         2.5	Out SOURCE Sat at 100 mA	Measure V <sub>CC2</sub> - V <sub>GATE</sub>		1.2	2.0	V
Out Fall Time $9.0 \text{ V} > \text{V}_{\text{GATE}} > 1.0 \text{ V}; \text{V}_{\text{CC1}} = \text{V}_{\text{CC2}} = 12 \text{ V}$ -         30         50         ns           Shoot-Through Current         Note 2         -         -         50         mA           V GATE Resistance         Resistor to LGND. Note 2         20         50         100         kΩ           V GATE Schottky         LGND to V GATE @ 10 mA         -         600         800         mV           Soft Start (SS)           Charge Time         -         1.6         3.3         5.0         ms           Pulse Period         25         100         200         ms           Duty Cycle         (Charge Time /Pulse Period) × 100         1.0         3.3         6.0         %           COMP Clamp Voltage         VFB = 0 V; VSS = 0         0.50         0.95         1.10         V           VFFB SS Fault Disable         VGATE = Low         0.9         1.0         1.1         V           High Threshold         -         -         2.5         3.0         V           PWM Comparator           Transient Response         VFFB = 0 to 5.0 V to V GATE = 9.0 V to 1.0 V; V to 1.0 V; V to 1.0	Out SINK Sat at 100 mA	Measure V <sub>GATE</sub> - V <sub>PGND</sub>	() - Q	1.0	1.5	V
Shoot-Through Current         Note 2         -         -         50         mA $V_{GATE}$ Resistance         Resistor to LGND. Note 2         20         50         100         kΩ $V_{GATE}$ Schottky         LGND to $V_{GATE}$ @ 10 mA         -         600         800         mV           Soft Start (SS)           Charge Time         -         1.6         3.3         5.0         ms           Pulse Period         25         100         200         ms           Duty Cycle         (Charge Time /Pulse Period) × 100         1.0         3.3         6.0         %           COMP Clamp Voltage $V_{FB} = 0$ V; $V_{SS} = 0$ 0.50         0.95         1.10         V           V <sub>FFB</sub> SS Fault Disable $V_{GATE} = Low$ 0.9         1.0         1.1         V           PWM Comparator           Transient Response $V_{FFB} = 0$ to 5.0 V to $V_{GATE} = 9.0$ V to 1.0 V; $V_{CC1} = V_{CC2} = 12$ V         -         100         125         ns	Out Rise Time	1.0 V < V <sub>GATE</sub> < 9.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V	3 70	30	50	ns
VGATE Resistance         Resistor to LGND. Note 2         20         50         100         kΩ           VGATE Schottky         LGND to VGATE @ 10 mA         -         600         800         mV           Soft Start (SS)           Charge Time         -         1.6         3.3         5.0         ms           Pulse Period         -         25         100         200         ms           Duty Cycle         (Charge Time /Pulse Period) × 100         1.0         3.3         6.0         %           COMP Clamp Voltage         VFB = 0 V; VSB = 0         0.50         0.95         1.10         V           VFFB SS Fault Disable         VGATE = Low         0.9         1.0         1.1         V           PWM Comparator           Transient Response         VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VGATE = 9.0 V to 1.0 V; VGC1 = VCC2 = 12 V         -         100         125         ns	Out Fall Time	9.0 V > V <sub>GATE</sub> > 1.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V	16.	30	50	ns
V <sub>GATE</sub> Schottky         LGND to V <sub>GATE</sub> @ 10 mA         −         600         800         mV           Soft Start (SS)           Charge Time         −         1.6         3.3         5.0         ms           Pulse Period         25         100         200         ms           Duty Cycle         (Charge Time /Pulse Period) × 100         1.0         3.3         6.0         %           COMP Clamp Voltage         V <sub>FB</sub> = 0 V; V <sub>SS</sub> = 0         0.50         0.95         1.10         V           V <sub>FFB</sub> SS Fault Disable         V <sub>GATE</sub> = Low         0.9         1.0         1.1         V           High Threshold         −         −         2.5         3.0         V           PWM Comparator           Transient Response         V <sub>FFB</sub> = 0 to 5.0 V to V <sub>GATE</sub> = 9.0 V to 1.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V         −         100         125         ns	Shoot-Through Current	Note 2	-	-	50	mA
Soft Start (SS)           Charge Time         -         1.6         3.3         5.0         ms           Pulse Period         -         25         100         200         ms           Duty Cycle         (Charge Time /Pulse Period) × 100         1.0         3.3         6.0         %           COMP Clamp Voltage         V <sub>FB</sub> = 0 V; V <sub>SS</sub> = 0         0.50         0.95         1.10         V           V <sub>FFB</sub> SS Fault Disable         V <sub>GATE</sub> = Low         0.9         1.0         1.1         V           High Threshold         -         -         2.5         3.0         V           PWM Comparator           Transient Response         V <sub>FFB</sub> = 0 to 5.0 V to V <sub>GATE</sub> = 9.0 V to 1.0 V; V <sub>CC1</sub> = 12 V         -         100         125         ns	V <sub>GATE</sub> Resistance	Resistor to LGND. Note 2	20	50	100	kΩ
Charge Time         -         1.6         3.3         5.0         ms           Pulse Period         -         25         100         200         ms           Duty Cycle         (Charge Time /Pulse Period) × 100         1.0         3.3         6.0         %           COMP Clamp Voltage         VFB = 0 V; VSS = 0         0.50         0.95         1.10         V           VFFB SS Fault Disable         VGATE = Low         0.9         1.0         1.1         V           High Threshold         -         -         2.5         3.0         V           PWM Comparator           Transient Response         VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V         -         100         125         ns	V <sub>GATE</sub> Schottky	LGND to V <sub>GATE</sub> @ 10 mA	-	600	800	mV
Pulse Period       25       100       200       ms         Duty Cycle       (Charge Time / Pulse Period) × 100       1.0       3.3       6.0       %         COMP Clamp Voltage $V_{FB} = 0 \text{ V}; V_{SS} = 0$ 0.50       0.95       1.10       V         V <sub>FFB</sub> SS Fault Disable $V_{GATE} = Low$ 0.9       1.0       1.1       V         High Threshold       -       -       2.5       3.0       V         PWM Comparator         Transient Response $V_{FFB} = 0 \text{ to } 5.0 \text{ V to } V_{GATE} = 9.0 \text{ V to } 1.0 \text{ V};$ $V_{CC1} = V_{CC2} = 12 \text{ V}$ -       100       125       ns	Soft Start (SS)	5 6 1				
	Charge Time	AHILA D-Y D.	1.6	3.3	5.0	ms
	Pulse Period	1 4 6	25	100	200	ms
VFFB SS Fault Disable         VGATE = Low         0.9         1.0         1.1         V           High Threshold         -         -         2.5         3.0         V           PWM Comparator           Transient Response         VFFB = 0 to 5.0 V to VGATE = 9.0 V to 1.0 V; VCC1 = VCC2 = 12 V         -         100         125         ns	Duty Cycle	(Charge Time /Pulse Period) × 100	1.0	3.3	6.0	%
High Threshold         -         -         2.5         3.0         V           PWM Comparator           Transient Response         V <sub>FFB</sub> = 0 to 5.0 V to V <sub>GATE</sub> = 9.0 V to 1.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V         -         100         125         ns	COMP Clamp Voltage	V <sub>FB</sub> = 0 V; V <sub>SS</sub> = 0	0.50	0.95	1.10	V
PWM Comparator           Transient Response         V <sub>FFB</sub> = 0 to 5.0 V to V <sub>GATE</sub> = 9.0 V to 1.0 V; V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V         -         100         125         ns	V <sub>FFB</sub> SS Fault Disable		0.9	1.0	1.1	V
Transient Response $V_{FFB} = 0$ to 5.0 V to $V_{GATE} = 9.0$ V to 1.0 V; $-$ 100 125 ns $V_{CC1} = V_{CC2} = 12$ V	High Threshold	-	-	2.5	3.0	V
V <sub>CC1</sub> = V <sub>CC2</sub> = 12 V	PWM Comparator		•		•	•
V <sub>FFB</sub> Bias Current V <sub>FFB</sub> = 0 V - 0.3 - μA	Transient Response		-	100	125	ns
	V <sub>FFB</sub> Bias Current	V <sub>FFB</sub> = 0 V	-	0.3	_	μΑ

<sup>2.</sup> Guaranteed by design, not 100% tested in production.

	Cha	racteris	stic		Test Conditions	Min	Тур	Max	Unit
DAC									
Input	Thresh	old			$V_{ID0}, V_{ID1},  V_{ID2},  V_{ID3},  V_{ID4}$	1.00	1.25	2.40	V
Input	Pull Up	Resista	ance		V <sub>ID0</sub> , V <sub>ID1</sub> , V <sub>ID2</sub> , V <sub>ID3</sub> , V <sub>ID4</sub>	25	50	100	kΩ
Pull l	Jp Volta	ge			-	4.85	5.00	5.15	V
Accur	acy (all	codes ex	xcept 11	111)	Measure V <sub>FB</sub> = COMP, 25°C ≤[T <sub>J</sub> ≤[] 25°C	-	_	1.0	%
$V_{\text{ID4}}$	V <sub>ID3</sub>	V <sub>ID2</sub>	V <sub>ID1</sub>	$V_{ID0}$					
0	1	1	1	1	-	1.3266	1.3400	1.3534	V
0	1	1	1	0	-	1.3761	1.3900	1.4039	V
0	1	1	0	1	-	1.4256	1.4400	1.4544	V
0	1	1	0	0	-	1.4751	1.4900	1.5049	V
0	1	0	1	1	-	1.5246	1.5400	1.5554	V
0	1	0	1	0	-	1.5741	1.5900	1.6059	V
0	1	0	0	1	-	1.6236	1.6400	1.6564	V
0	1	0	0	0	A -	1.6731	1,6900	1.7069	V
0	0	1	1	1		1.7226	1.7400	1.7574	V
0	0	1	1	0		1,7721	1.7900	1.8079	V
0	0	1	0	1	- 0,5	1.8216	1.8400	1.8584	V
0	0	1	0	0	- 0 <sup>V</sup> , 6	1.8711	1.8900	1.9089	V
0	0	0	1	1	- 15 01	1,9206	1.9400	1.9594	V
0	0	0	1	0	-c.VQ.	1.9701	1.9900	2.0099	V
0	0	0	0	1	110 01, 50.	2.0196	2.0400	2.0604	V
0	0	0	0	0	- V V	2.0691	2.0900	2.1109	V
1	1	1	1	1	-G- C- 1	1.2191	1.2440	1.2689	V
1	1	1	1	0	A - A - IN.	2.1186	2.1400	2.1614	V
1	1	1	0	1	1,67,-67	2.2176	2.2400	2.2624	V
1	1	1	0	0	CO, CK	2.3166	2.3400	2.3634	V
1	1	0	1	1	4. 64 -	2.4156	2.4400	2.4644	V
1	1	0	1	0	S , R -	2.5146	2.5400	2.5654	V
1	1	0	0	.1	-	2.6136	2.6400	2.6664	V
1	1	0	0	0	-	2.7126	2.7400	2.7674	V
1	0	1	1	1	-	2.8116	2.8400	2.8684	V
1	0	1	1	0	_	2.9106	2.9400	2.9694	V
1	0	1	0	1	_	3.0096	3.0400	3.0704	V
1	0	1	0	0	_	3.1086	3.1400	3.1714	V
1	0	0	1	1	_	3.2076	3.2400	3.2724	V
1	0	0	1	0	_	3.3066	3.3400	3.3734	V
1	0	0	0	1	_	3.4056	3.4400	3.4744	V
1	0	0	0	0		3.5046	3.5400	3.5754	V

Characteristic Test Conditions		Min	Тур	Max	Unit
Supply Current	,				
I <sub>CC1</sub>	No Switching	-	8.5	13.5	mA
I <sub>CC2</sub>	No Switching	-	1.6	3.0	mA
Operating I <sub>CC1</sub>	V <sub>FB</sub> = COMP = V <sub>FFB</sub>	-	8.0	13	mA
Operating I <sub>CC2</sub>	V <sub>FB</sub> = COMP = V <sub>FFB</sub>	-	2.0	5.0	mA
C <sub>OFF</sub>					
Normal Charge Time	V <sub>FFB</sub> = 1.5 V; V <sub>SS</sub> = 5.0 V	1.0	1.6	2.2	μs
Extension Charge Time	V <sub>SS</sub> = V <sub>FFB</sub> = 0	5.0	8.0	11.0	μS
Discharge Current	C <sub>OFF</sub> to 5.0 V; V <sub>FB</sub> > 1.0 V	5.0	-	-	mA
Time Out Timer				0	
Time Out Time	V <sub>FB</sub> = V <sub>COMP</sub> ; V <sub>FFB</sub> = 2.0 V; Record V <sub>GATE</sub> Pulse High Duration	10	30	65	μs
Fault Mode Duty Cycle	V <sub>FFB</sub> = 0V	35	50	70	%

# PACKAGE PIN DESCRIPTION

PACKAGE PIN #		(E. CO. 410
SO-16	PIN SYMBOL	FUNCTION
1, 2, 3, 4, 6	V <sub>ID0</sub> -V <sub>ID4</sub>	Voltage ID DAC input pins. These pins are internally pulled up to 5.0 V providing logic ones if left open. $V_{ID4}$ selects the DAC range. When $V_{ID4}$ is High (logic one), the DAC range is 2.14 V to 3.54 V with 100 mV increments. When $V_{ID4}$ is Low (logic zero), the DAC range is 1.34 V to 2.09 V with 50 mV increments. $V_{ID0} - V_{ID4}$ select the desired DAC output voltage. Leaving all 5 DAC input pins open results in a DAC output voltage of 1.244 V, allowing for adjustable output voltage, using a traditional resistor divider.
5	ss HIS	Soft Start Pin. A capacitor from this pin to LGND in conjunction with internal 60 $\mu$ A current source provides Soft Start function for the controller. This pin disables fault detect function during Soft Start. When a fault is detected, the Soft Start capacitor is slowly discharged by internal 2.0 $\mu$ A current source setting the time out before trying to restart the IC. Charge/discharge current ratio of 30 sets the duty cycle for the IC when the regulator output is shorted.
7	C <sub>OFF</sub>	A capacitor from this pin to ground sets the time duration for the on board one shot, which is used for the constant off time architecture.
8	V <sub>FFB</sub>	Fast feedback connection to the PWM comparator. This pin is connected to the regulator output. The inner feedback loop terminates on time.
9	V <sub>CC2</sub>	Boosted power for the gate driver.
10	V <sub>GATE</sub>	MOSFET driver pin capable of 1.5 A peak switching current.
11	PGND	High current ground for the IC. The MOSFET driver is referenced to this pin. Input capacitor ground and the anode of the Schottky diode should be tied to this pin.
12	NC	No connection.
13	V <sub>CC1</sub>	Input power for the IC.
14	LGND	Signal ground for the IC. All control circuits are referenced to this pin.
15	COMP	Error amplifier compensation pin. A capacitor to ground should be provided externally to compensate the amplifier.
16	V <sub>FB</sub>	Error amplifier DC feedback input. This is the master voltage feedback which sets the output voltage. This pin can be connected directly to the output or a remote sense trace.

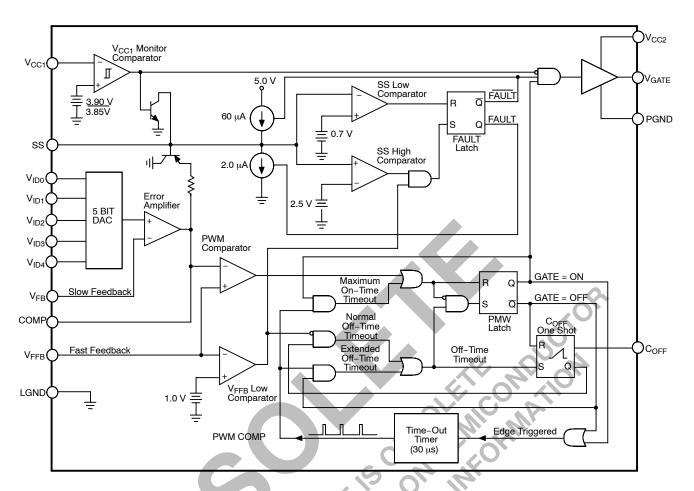


Figure 2. Block Diagram

### **APPLICATIONS INFORMATION**

#### THEORY OF OPERATION

#### V<sup>2</sup> Control Method

The  $V^2$  method of control uses a ramp signal that is generated by the ESR of the output capacitors. This ramp is proportional to the AC current through the main inductor and is offset by the value of the DC output voltage. This control scheme inherently compensates for variation in either line or load conditions, since the ramp signal is generated from the output voltage itself. This control scheme inherently compensates for variation in either line or load conditions, since the ramp signal is generated from the output voltage itself. This control scheme differs from traditional techniques such as voltage mode, which generates an artificial ramp, and current mode, which generates a ramp from inductor current.

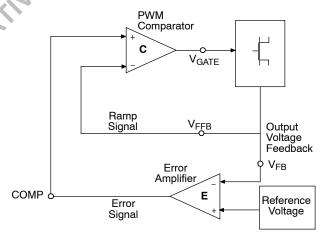


Figure 3. V<sup>2</sup> Control Diagram

The  $V^2$  control method is illustrated in Figure 3. The output voltage is used to generate both the error signal and the ramp signal. Since the ramp signal is simply the output voltage, it is affected by any change in the output regardless of the origin of that change. The ramp signal also contains the DC portion of the output voltage, which allows the control circuit to drive the main switch to 0% or 100% duty cycle as required.

A change in line voltage changes the current ramp in the inductor, affecting the ramp signal, which causes the  $V^2$  control scheme to compensate the duty cycle. Since the change in inductor current modifies the ramp signal, as in current mode control, the  $V^2$  control scheme has the same advantages in line transient response.

A change in load current will have an affect on the output voltage, altering the ramp signal. A load step immediately changes the state of the comparator output, which controls the main switch. Load transient response is determined only by the comparator response time and the transition speed of the main switch. The reaction time to an output load step has no relation to the crossover frequency of the error signal loop, as in traditional control methods.

The error signal loop can have a low crossover frequency, since transient response is handled by the ramp signal loop. The main purpose of this 'slow' feedback loop is to provide DC accuracy. Noise immunity is significantly improved, since the error amplifier bandwidth can be rolled off at a low frequency. Enhanced noise immunity improves remote sensing of the output voltage, since the noise associated with long feedback traces can be effectively filtered.

Line and load regulation are drastically improved because there are two independent voltage loops. A voltage mode controller relies on a change in the error signal to compensate for a deviation in either line or load voltage. This change in the error signal causes the output voltage to change corresponding to the gain of the error amplifier, which is normally specified as line and load regulation. A current mode controller maintains fixed error signal under deviation in the line voltage, since the slope of the ramp signal changes, but still relies on a change in the error signal for a deviation in load. The V<sup>2</sup> method of control maintains a fixed error signal for both line and load variation, since the ramp signal is affected by both line and load.

#### **Constant Off Time**

To maximize transient response, the CS5156H uses a constant off time method to control the rate of output pulses. During normal operation, the off time of the high side switch is terminated after a fixed period, set by the  $C_{OFF}$  capacitor. To maintain regulation, the  $V^2$  control loop varies switch on time. The PWM comparator monitors the output voltage ramp, and terminates the switch on time.

Constant off time provides a number of advantages. Switch duty cycle can be adjusted from 0 to 100% on a pulse by pulse basis when responding to transient conditions. Both 0% and 100% duty cycle operation can be maintained for extended periods of time in response to load or line transients. PWM slope compensation to avoid sub–harmonic oscillations at high duty cycles is avoided.

Switch on time is limited by an internal 30 µs timer, minimizing stress to the power components.

#### **Programmable Output**

The CS5156H is designed to provide two methods for programming the output voltage of the power supply. A five bit on board digital to analog converter (DAC) is used to program the output voltage within two different ranges. The first range is 2.14 V to 3.54 V in 100 mV steps, the second is 1.34 V to 2.09 V in 50 mV steps, depending on the digital input code. If all five bits are left open, the CS5156H enters adjust mode. In adjust mode, the designer can choose any output voltage by using resistor divider feedback to the  $V_{\rm FB}$  and  $V_{\rm FFB}$  pins, as in traditional controllers. The CS5156H is specifically designed to be backwards compatible with the CS5151H, which uses a four bit DAC code.

#### Start Up

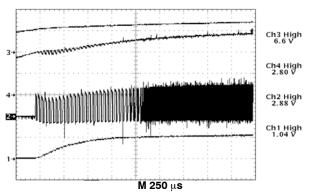
Until the voltage on the  $V_{CC1}$  supply pin exceeds the 3.9 V monitor threshold, the Soft Start and gate pins are held low. The FAULT latch is reset (no Fault condition). The output of the error amplifier (COMP) is pulled up to 1.0 V by the comparator clamp. When the  $V_{CC1}$  pin exceeds the monitor threshold, the GATE output is activated, and the Soft Start capacitor begins charging. The GATE output will remain on, enabling the NFET switch, until terminated by either the PWM comparator, or the maximum on time timer.

If the maximum on time is exceeded before the regulator output voltage achieves the 1.0 V level, the pulse is terminated. The GATE pin drives low for the duration of the extended off time. This time is set by the time out timer and is approximately equal to the maximum on time, resulting in a 50% duty cycle. Then, the GATE pin will drive high, and the cycle repeats.

When regulator output voltage achieves the 1.0 V level present at the COMP pin, regulation has been achieved and normal off time will ensue. The PWM comparator terminates the switch on time, with off time set by the  $C_{OFF}$  capacitor. The  $V^2$  control loop will adjust switch duty cycle as required to ensure the regulator output voltage tracks the output of the error amplifier.

The Soft Start and COMP capacitors will charge to their final levels, providing a controlled turn on of the regulator output. Regulator turn on time is determined by the COMP capacitor charging to its final value. Its voltage is limited by

the Soft Start COMP clamp and the voltage on the Soft Start pin (see Figures 4 and 5).



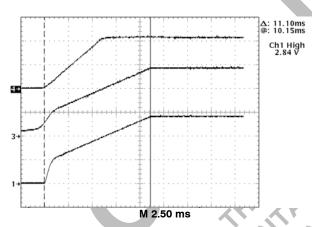
Trace 1 - Regulator Output Voltage (1.0 V/div.)

Trace 2- Inductor Switching Node (2.0 V/div.)

Trace 3- 12 V Input (V<sub>CC1</sub> and V<sub>CC2</sub>) (5.0 V/div.)

Trace 4- 5.0 V Input (1.0 V/div.)

Figure 4. CS5156H Demonstration Board Startup in Response to Increasing 12 V and 5.0 V Input Voltages. Extended Off Time is Followed by Normal Off Time Operation when Output Voltage Achieves Regulation to the Error Amplifier Output.



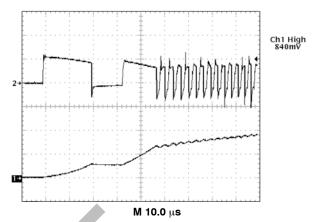
Trace 1- Regulator Output Voltage (1.0 V/div.)

Trace 3- COMP PIn (error amplifier output) (1.0 V/div.)

Trace 4- Soft Start Pin (2.0 V/div.)

Figure 5. CS5156H Demonstration Board Startup Waveforms

If the input voltage rises quickly, or the regulator output is enabled externally, output voltage will increase to the level set by the error amplifier output more rapidly, usually within a couple of cycles (see Figure 6).



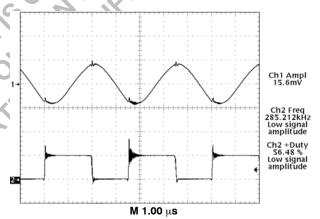
Trace 1- Regulator Output Voltage (5.0 V/div.)

Trace 2- Inductor Switching Node (5.0 V/div.)

Figure 6. CS5156H Demonstration Board Enable Startup Waveforms

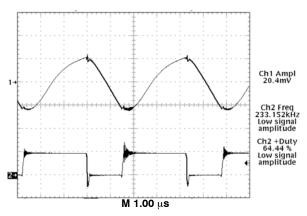
#### **Normal Operation**

During normal operation, switch off time is constant and set by the  $C_{OFF}$  capacitor. Switch on time is adjusted by the  $V^2$  control loop to maintain regulation. This results in changes in regulator switching frequency, duty cycle, and output ripple in response to changes in load and line. Output voltage ripple will be determined by inductor ripple current working into the ESR of the output capacitors (see Figures 7 and 8).



Trace 1- Regulator Output Voltage (10 mV/div.)
Trace 2- Inductor Switching Node (5.0 V/div.)

Figure 7. Peak-to-Peak Ripple on  $V_{OUT}$  = 2.8 V,  $I_{OUT}$  = 0.5 A (Light Load)



Trace 1- Regulator Output Voltage (10 mV/div.)
Trace 2- Inductor Switching Node (5.0 V/div.)

Figure 8. Peak-to-Peak Ripple on V<sub>OUT</sub> = 2.8 V, I<sub>OUT</sub> = 13 A (Heavy Load)

#### **Transient Response**

The CS5156H  $V^2$  control loop's 100 ns reaction time provides unprecedented transient response to changes in input voltage or output current. Pulse by pulse adjustment of duty cycle is provided to quickly ramp the inductor current to the required level. Since the inductor current cannot be changed instantaneously, regulation is maintained by the output capacitor(s) during the time required to slew the inductor current.

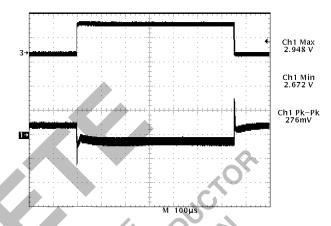
Overall load transient response is further improved through a feature called "adaptive voltage positioning". This technique pre-positions the output capacitor's voltage to reduce total output voltage excursions during changes in load.

Holding tolerance to 1.0% allows the error amplifier's reference voltage to be targeted +40 mV high without compromising DC accuracy. A "droop resistor", implemented through a PC board trace, connects the error amplifier's feedback pin ( $V_{FB}$ ) to the output capacitors and load and carries the output current. With no load, there is no DC drop across this resistor, producing an output voltage tracking the error amplifier's, including the +40 mV offset. When the full load current is delivered, an 80 mV drop is developed across this resistor. This results in output voltage being offset –40 mV low.

The result of adaptive voltage positioning is that additional margin is provided for a load transient before reaching the output voltage specification limits. When load current suddenly increases from its minimum level, the output capacitor is pre-positioned +40 mV. Conversely, when load current suddenly decreases from its maximum

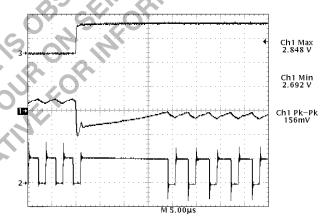
level, the output capacitor is pre-positioned -40 mV (see Figures 9, 10, and 11). For best transient response, a combination of a number of high frequency and bulk output capacitors are usually used.

If the maximum on time is exceeded while responding to a sudden increase in load current, a normal off time occurs to prevent saturation of the output inductor.



Trace 1- Regulator Output Voltage (1.0 V/div.)
Trace 2- Regulator Output Voltage (20 V/div.)

Figure 9. CS5156H Demonstration Board Response to a 0.5 to 13 A Load Pulse (Output Set for 2.8 V)

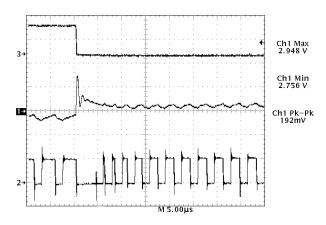


Trace 1- Regulator Output Voltage (1.0 V/div.)

Trace 2- Inductor Switching Node (5.0 V/div.)

Trace 3- Output Current (0.5 to 13 Amps) (20 V/div.)

Figure 10. CS5156H Demonstration Board Response to 13 A Load Turn On (Output Set for 2.8 V). Upon Completing a Normal Off Time, The V<sup>2</sup> Control Loop Immediately Connects the Inductor to the Input Voltage, Providing 100% Duty Cycle. Regulation is Achieved in Less Than 20 μs



Trace 1- Regulator Output Voltage (1.0 V/div.)

Trace 2- Inductor Switching Node (5.0 V/div.)

Trace 3- Output Current (13 to 0,5 Amps) (20 mV/div.)

Figure 11. CS5156H Demonstration Board Response to 13 A Load Turn Off (Output Set for 2.8 V). V<sup>2</sup> Control Topology Immediately Connects Inductor to Ground, Providing 0% Duty Cycle. Regulation is Achieved in Less Than 10 μs

#### PROTECTION AND MONITORING FEATURES

#### V<sub>CC1</sub> Monitor

To maintain predictable startup and shutdown characteristics an internal  $V_{CC1}$  monitor circuit is used to prevent the part from operating below 3.75 V minimum startup. The  $V_{CC1}$  monitor comparator provides hysteresis and guarantees a 3.70 V minimum shutdown threshold.

#### **Short Circuit Protection**

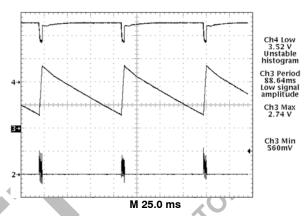
A lossless hiccup mode short circuit protection feature is provided, requiring only the Soft Start capacitor to implement. If a short circuit condition occurs ( $V_{FFB} < 1.0 \text{ V}$ ), the  $V_{FFB}$  low comparator sets the FAULT latch. This causes the MOSFET to shut off, disconnecting the regulator from it's input voltage. The Soft Start capacitor is then slowly discharged by a 2.0  $\mu$ A current source until it reaches it's lower 0.7 V threshold. The regulator will then attempt to restart normally, operating in it's extended off time mode with a 50% duty cycle, while the Soft Start capacitor is charged with a 60  $\mu$ A charge current.

If the short circuit condition persists, the regulator output will not achieve the 1.0 V low  $V_{FFB}$  comparator threshold before the Soft Start capacitor is charged to it's upper 2.5 V threshold. If this happens the cycle will repeat itself until the short is removed. The Soft Start charge/discharge current ratio sets the duty cycle for the pulses (2.0  $\mu$ A/60  $\mu$ A = 3.3%), while actual duty cycle is half that due to the extended off time mode (1.65%).

This protection feature results in less stress to the regulator components, input power supply, and PC board

traces than occurs with constant current limit protection (see Figures 12 and 13).

If the short circuit condition is removed, output voltage will rise above the 1.0 V level, preventing the FAULT latch from being set, allowing normal operation to resume.

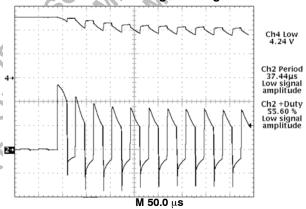


Trace 4- 5.0 V Supply Voltage (2.0 V/div.)

Trace 3- Soft Start Timing Capacitor (1.0 V/div.)

Trace 2- Inductor Switching Node (2.0 V/div.)

Figure 12. CS5156H Demonstration Board Hiccup Mode Short Circuit Protection. Gate Pulses are Delivered While the Soft Start Capacitor Charges, and Cease During Discharge



Trace 4- 5.0 V from PC Power Supply (2.0 V/div.)

Trace 2- Inductor Switching Node (2.0 V/div.)

Figure 13. Startup with Regulator Output Shorted

#### **Overvoltage Protection**

Overvoltage protection (OVP) is provided as result of the normal operation of the  $V^2$  control topology and requires no additional external components. The control loop responds to an overvoltage condition within 100 ns, causing the top MOSFET to shut off, disconnecting the regulator from it's input voltage.

#### **External Output Enable Circuit**

On/off control of the regulator can be implemented through the addition of two additional discrete components

(see Figure 14). This circuit operates by pulling the Soft Start pin high, and the  $V_{FFB}$  pin low, emulating a short circuit condition.

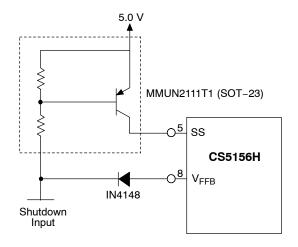


Figure 14. Implementing Shutdown with the CS5156H

#### **External Power Good Circuit**

An optional Power Good signal can be generated through the use of four additional external components (see Figure 15). The threshold voltage of the Power Good signal can be adjusted per the following equation:

$$V_{Power Good} = \frac{(R1 + R2) \times 0.65 V}{R2}$$

This circuit provides an open collector output that drives the Power Good output to ground for regulator voltages less than  $V_{Power\ Good}$ .

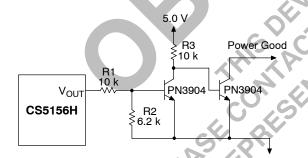
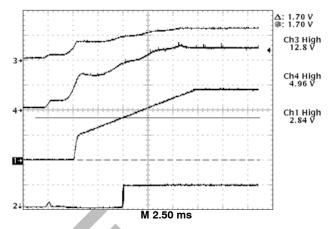


Figure 15. Implementing Power Good with the CS5156H



Trace 3 - 12 V Input (V<sub>CC1</sub>) and (V<sub>CC2</sub>) (10 V/div.)

Trace 4- 5.0 V Input (2.0 V/div.)

Trace 1 - Regulator Output Voltage (1.0 V/div.)

Trace 2- Power Good Signal (2.0 V/div.)

Figure 16. CS5156H Demonstration Board During Power Up. Power Good Signal is Activated when Output Voltage Reaches 1.70 V.

#### **Selecting External Components**

The CS5156H can be used with a wide range of external power components to optimize the cost and performance of a particular design. The following information can be used as general guidelines to assist in their selection.

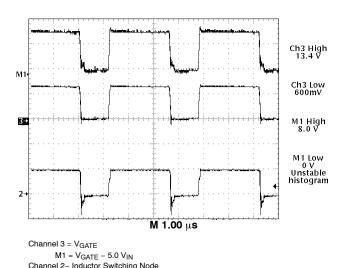
#### **NFET Power Transistors**

Both logic level and standard MOSFETs can be used. The reference designs derive gate drive from the 12 V supply which is generally available in most computer systems and use logic level MOSFETs. A charge pump may be easily implemented to permit use of standard MOSFETs or support 5.0 V or 12 V only systems (maximum of 20 V). Multiple MOSFETs may be paralleled to reduce losses and improve efficiency and thermal management.

Voltage applied to the MOSFET gates depends on the application circuit used. The gate driver output is specified to drive to within 1.5 V of ground when in the low state and to within 2.0 V of its bias supply when in the high state. In practice, the MOSFET gates will be driven rail to rail due to overshoot caused by the capacitive load they present to the controller IC. For the typical application where  $V_{\rm CC1} = V_{\rm CC2} = 12$  V and 5.0 V is used as the source for the regulator output current, the following gate drive is provided;

$$V_{GATE} = 12 V - 5.0 V = 7.0 V$$

(see Figure 17.)



# Figure 17. CS5156H Gate Drive Waveforms Depicting Rail to Rail Swing

The most important aspect of MOSFET performance is RDS<sub>ON</sub>, which effects regulator efficiency and MOSFET thermal management requirements.

The power dissipated by the MOSFETs and the Schottky diode may be estimated as follows;

Switching MOSFET:

Power = 
$$I_{LOAD}^2 \times RDS_{ON} \times duty$$
 cycle Schottky diode:

#### Off Time Capacitor (COFF)

The C<sub>OFF</sub> timing capacitor sets the regulator off time:

TOFF = 
$$COFF \times 4848.5$$

When the  $V_{FFB}$  pin is less than 1.0 V, the current charging the  $C_{OFF}$  capacitor is reduced. The extended off time can be calculated as follows:

$$TOFF = COFF \times 24,242.5$$

Off time will be determined by either the  $T_{OFF}$  time, or the time out timer, whichever is longer.

The preceding equations for duty cycle can also be used to calculate the regulator switching frequency and select the  $C_{OFF}$  timing capacitor:

$$C_{OFF} = \frac{Perioid \times (1 - duty cycle)}{4848.5}$$

where:

$$Period = \frac{1}{switching frequency}$$

#### "Droop" Resistor for Adaptive Voltage Positioning

Adaptive voltage positioning is used to reduce output voltage excursions during abrupt changes in load current. Regulator output voltage is offset +40 mV when the

regulator is unloaded, and -40 mV at full load. This results in increased margin before encountering minimum and maximum transient voltage limits, allowing use of less capacitance on the regulator output (see Figure 9).

To implement adaptive voltage positioning, a "droop" resistor must be connected between the output inductor and output capacitors and load. This is normally implemented by a PC board trace of the following value:

$$R_{DROOP} = \frac{80 \text{ mV}}{I_{MAX}}$$

Adaptive voltage positioning can be disabled for improved DC regulation by connecting the V<sub>FB</sub> pin directly to the load using a separate, non-load current carrying circuit trace.

#### **Input and Output Capacitors**

These components must be selected and placed carefully to yield optimal results. Capacitors should be chosen to provide acceptable ripple on the input supply lines and regulator output voltage. Key specifications for input capacitors are their ripple rating, while ESR is important for output capacitors. For best transient response, a combination of low value/high frequency and bulk capacitors placed close to the load will be required.

#### **Output Inductor**

The inductor should be selected based on its inductance, current capability, and DC resistance. Increasing the inductor value will decrease output voltage ripple, but degrade transient response.

#### THERMAL MANAGEMENT

# Thermal Considerations for Power MOSFETs and Diodes

In order to maintain good reliability, the junction temperature of the semiconductor components should be kept to a maximum of 150°C or lower. The thermal impedance (junction to ambient) required to meet this requirement can be calculated as follows:

Thermal Impedance = 
$$\frac{T_{JUNCTION(MAX)} - T_{AMBIENT}}{Power}$$

A heatsink may be added to TO-220 components to reduce their thermal impedance. A number of PC board layout techniques such as thermal vias and additional copper foil area can be used to improve the power handling capability of surface mount components.

#### **EMI Management**

As a consequence of large currents being turned on and off at high frequency, switching regulators generate noise as a consequence of their normal operation. When designing for compliance with EMI/EMC regulations, additional components may be added to reduce noise emissions. These components are not required for regulator operation and experimental results may allow them to be eliminated. The input filter inductor may not be required because bulk filter

and bypass capacitors, as well as other loads located on the board will tend to reduce regulator di/dt effects on the circuit board and input power supply. Placement of the power component to minimize routing distance will also help to reduce emissions.

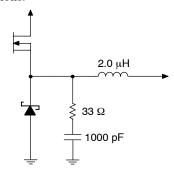


Figure 18. Filter Components

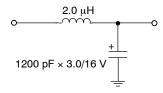


Figure 19. Input Filter

#### **Layout Guidelines**

- 1. Place 12 V filter capacitor next to the IC and connect capacitor ground to pin 11 (PGND).
- 2. Connect pin 11 (PGND) with a separate trace to the ground terminals of the 5.0 V input capacitors.
- 3. Place fast feedback filter capacitor next to pin 8 (V<sub>FFB</sub>) and connect it's ground terminal with a separate, wide trace directly to pin 14 (LGND).
- 4. Connect the ground terminals of the Compensation capacitor directly to the ground of the fast feedback filter capacitor to prevent common mode noise from effecting the PWM comparator.
- 5. Place the output filter capacitor(s) as close to the load as possible and connect the ground terminal to pin 14 (LGND).
- 6. To implement adaptive voltage positioning, connect both slow and fast feedback pins 16 ( $V_{FB}$ ) and 8 ( $V_{FFB}$ ) to the regulator output right at the inductor terminal. Connect inductor to the output capacitors via a trace with the following resistance:

$$R_{TRACE} = \frac{80 \text{ mV}}{I_{MAX}}$$

This causes the output voltage to be +40 mV with no load, and -40 mV with a full load, improving regulator transient response. This trace must be wide enough to carry the full output current. (Typical trace is 1.0 inch long, 0.17 inch wide). Care should be taken to minimize any additional losses after the feedback connection point to maximize regulation.

- 7. If DC regulation is to be optimized (at the expense of degraded transient regulation), adaptive voltage positioning can be disabled by connecting to V<sub>FB</sub> pin directly to the load with a separate trace (remote sense).
- Place 5.0 V input capacitors close to the switching MOSFET.

Route gate drive signals  $V_{GATE}$  (pin 10) with a trace that is a minimum of 0.025 inches wide.

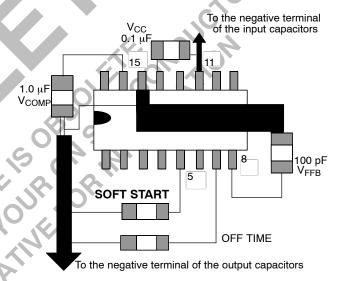


Figure 20. Layout Guidelines

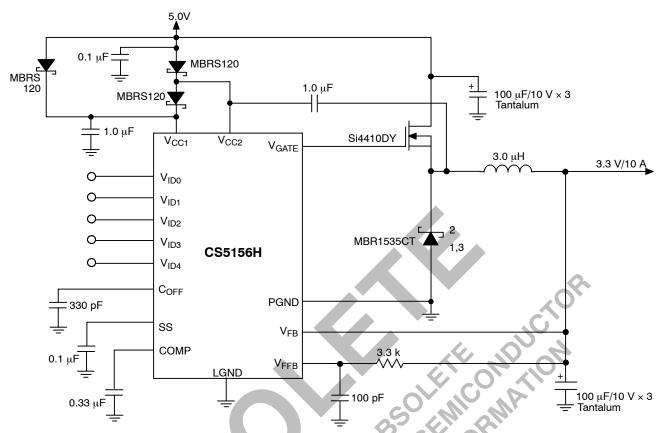


Figure 21. Additional Application Diagram, 5.0 V to 3.3 V/10 A Converter

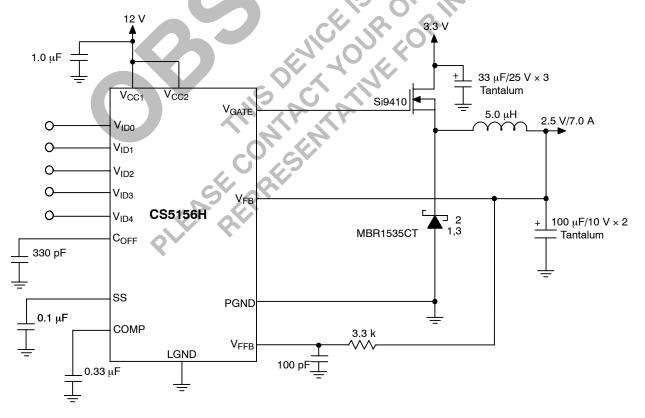


Figure 22. Additional Application Diagram, 3.3 V to 2.5 V/7.0 A Converter with 12 V Bias

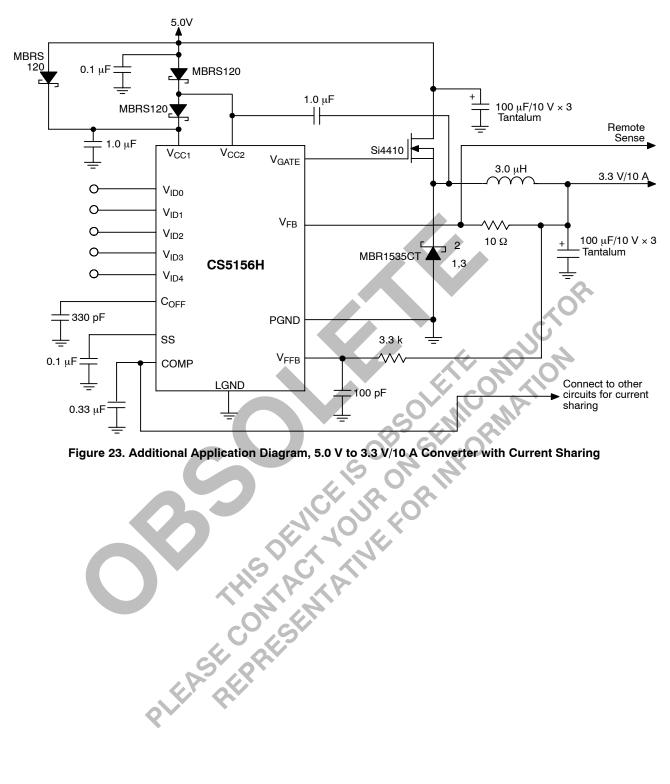
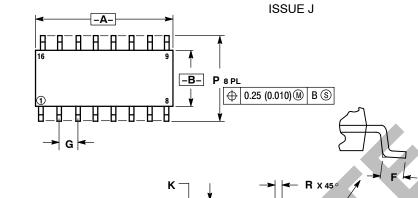


Figure 23. Additional Application Diagram, 5.0 V to 3.3 V/10 A Converter with Current Sharing

#### PACKAGE DIMENSIONS

### SO-16 **D SUFFIX**

CASE 751B-05



С

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
  DIMENSIONS A AND B DO NOT INCLUDE
- MOLD PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  DIMENSION D DOES NOT INCLUDE DAMBAR
- DIMENSION D DUES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABLE DAMBAR
  PROTRUSION SHALL BE 0.127 (0.005) TOTAL
  IN EXCESS OF THE D DIMENSION AT
  MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	1 7°	0°	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

#### PACKAGE THERMAL DATA

⊕ 0.25 (0.010) M T B S A S

D 16 PL

Parameter		SO-16	Unit
R <sub>OJC</sub>	Typical	28	°C/W
$R_{\Theta JA}$	Typical	115	°C/W
EASE CONT.	CIATA	St FO	
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